TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

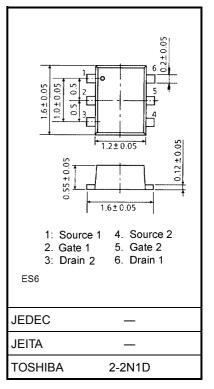
SSM6N16FE

High Speed Switching Applications Analog Switching Applications

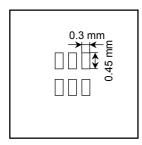
- Suitable for high-density mounting due to compact package
 - Low on resistance: $R_{on} = 3.0 \Omega (max) (@V_{GS} = 4 V)$
 - $: R_{on} = 4.0 \Omega (max) (@V_{GS} = 2.5 V)$
 - $: R_{on} = 15 \Omega (max) (@V_{GS} = 1.5 V)$

Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

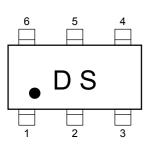
Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V _{DS}	20	V	
Gate-Source voltage		V _{GSS}	±10	V	
Drain current	DC	۱ _D	100	mA	
	Pulse	I _{DP}	200		
Drain power dissipation (Ta = 25° C)		P _D (Note)	150	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	



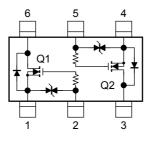
Note: Total rating, mounted on FR4 board (25.4 mm \times 25.4 mm \times 1.6 t, Cu Pad: 0.135 mm² \times 6)



Marking



Equivalent Circuit



Handling Precaution

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

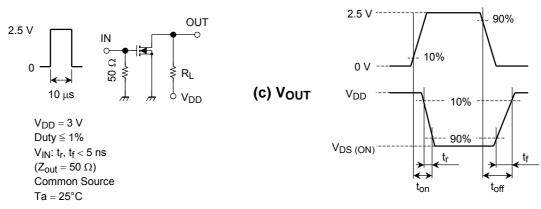
Unit: mm

Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS}=\pm 10~V,~V_{DS}=0$	_		±1	μA
Drain-Source breakdown voltage		V (BR) DSS	$I_D = 0.1 \text{ mA}, V_{GS} = 0$	20			V
Drain cut-off curre	ent	I _{DSS}	$V_{DS}=20~V,~V_{GS}=0$	_	_	1	μA
Gate threshold vo	oltage	V _{th}	$V_{DS} = 3 V, I_D = 0.1 mA$	0.6		1.1	V
Forward transfer	admittance	Y _{fs}	$V_{DS} = 3 V, I_D = 10 mA$	40			mS
Drain-Source ON resistance		R _{DS (ON)}	$I_D = 10 \text{ mA}, V_{GS} = 4 \text{ V}$	_	1.5	3.0	Ω
			$I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$	_	2.2	4.0	
			$I_D = 1 \text{ mA}, V_{GS} = 1.5 \text{ V}$		5.2	15	
Input capacitance		C _{iss}	$V_{DS} = 3 V, V_{GS} = 0, f = 1 MHz$		9.3		pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 3 V, V_{GS} = 0, f = 1 MHz$		4.5		pF
Output capacitance		C _{oss}	$V_{DS} = 3 V, V_{GS} = 0, f = 1 MHz$		9.8		pF
Switching time	Turn-on time	t _{on}	$V_{DD} = 3 \text{ V}, \text{ I}_{D} = 10 \text{ mA}, V_{GS} = 0 \sim 2.5 \text{ V}$	_	70		ns
	Turn-off time	t _{off}		_	125		

Switching Time Test Circuit

(a) Test circuit



(b) V_{IN}

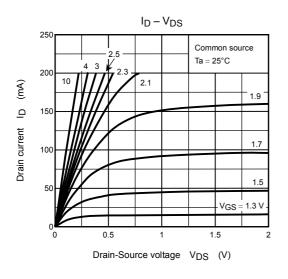
Precaution

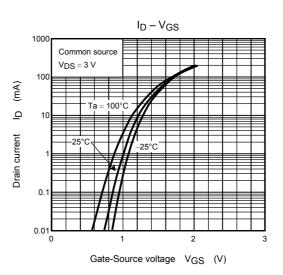
 V_{th} can be expressed as voltage between gate and source when low operating current value is $I_D = 100 \ \mu A$ for this product. For normal switching operation, V_{GS} (on) requires higher voltage than V_{th} and V_{GS} (off) requires lower voltage than V_{th} . (Relationship can be established as follows: V_{GS} (off) $< V_{th} < V_{GS}$ (on))

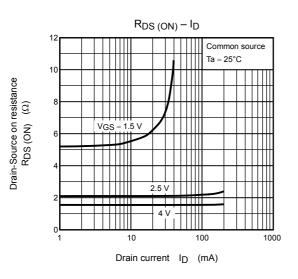
Please take this into consideration for using the device. V_{GS} recommended voltage of 1.5 V or higher to turn on this product.

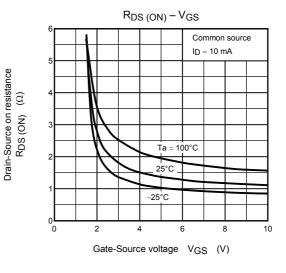
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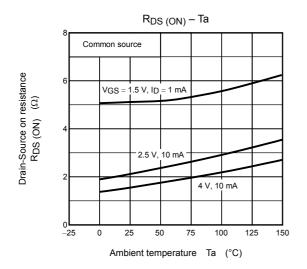
(Q1, Q2 common)

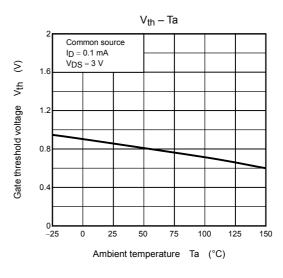






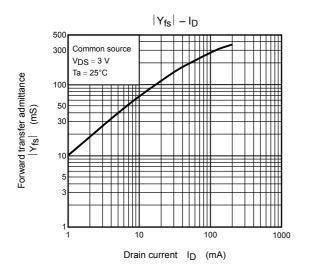


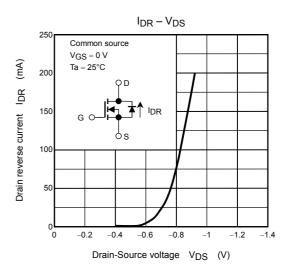


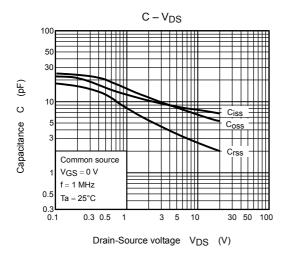


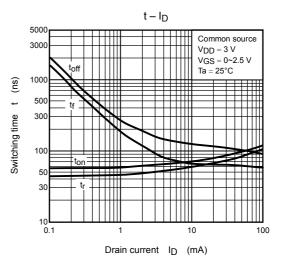
TOSHIBA

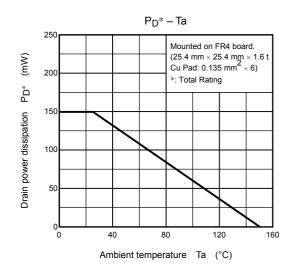
(Q1, Q2 common)











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